Microstructure and phase transformation of Ni-Mn-Ga wires produced by the in rotating water melt-spinning technique

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Abstract. Shape memory Ni₅₅Mn₂₀.₆Ga₂₄.₄(at%) wires of approximately 200μm in diameter were produced by the in rotating water melt-spinning technique (INROWASP). The microstructure of Ni-Mn-Ga wire was changed from dendritic-like into bamboo grains structure with only one crystal in the radial direction by annealing. Annealed wires exhibit sharp and well-defined transformation between austenite and martensite, A_p to 82.4 ℃, M_p to 70.5 ℃. The crystal structure of annealed wires presents non-moderated martensite and preferred orientation at (622).

Introduction

Ni-Mn-Ga ferromagnetic shape memory alloys (FSMAs) have triggered great interest for their high magnetic-field-induced strain (MFIS) up to 6%-12%, which are expected for actuators, sensors and dampers [1-3]. However, such large MFIS value is attained in single crystals but not in polycrystalline materials (less than of 1% of MFIS) due to constraints by grain boundaries on the motion of twin boundaries[4]. Moreover, bulk alloy material exhibits large current loss at high frequency [5]. To solve these problems, small size Ni-Mn-Ga alloys(e.g., wires, ribbons, films) and "constructs" from these structural elements (e.g., mats, laminates, textiles, foams and composites) are widely studied by various researchers [6-15]. These materials have presented superior properties by matching grain and sample sizes [15].

Ni-Mn-Ga wires or ribbons were usually fabricated by the Taylor-Ulitovsky method and melt spinning(and the related melt extraction method). The Taylor-Ulitovsky method often led to the trouble of removing glass sheath while the film-like shape wires fabricated by most of melt spun wires usually limit the application of Ni-Mn-Ga alloys, especially about Ni-Mn-Ga/polymer composites[6-15]. In rotating water melt-spinning (INROWASP) technique can achieve wires thin round shape [16]. Moreover, the microstructure and phase transformation of this thin round shape Ni-Mn-Ga wires have not been thoroughly investigated, and these are of great importance in the properties and application of Ni-Mn-Ga alloys. In the present article, Ni₅₅Mn₂₀.₆Ga₂₄.₄ wires, with 200μm diameter and thin round shape, were made by INROWASP technique and investigated in terms of microstructure and phase transformation.

Experimental

Ni₅₅Mn₂₀.₆Ga₂₄.₄ (at%) ferromagnetic memory alloy ingot was prepared by vacuum arc remelting (VAR) of high purity elements. Ni₅₅Mn₂₀.₆Ga₂₄ wires were obtained by INROWASP, which was similar to that previously reported in Refs [10, 16]. The process was summarized briefly here. A jet of molten alloy is ejected through a nozzle (200μm in diameter) into a rotating liquid cooling layer at a speed of 8m/s. The ejection gas pressure of high purity Ar was 0.08Mpa and ejection angle was 40°. The nozzle tip-water distance was 3-5mm.

Pieces of Ni₅₅Mn₂₀.₆Ga₂₄ wires were sealed into a vacuum quartz ampoule and then the ampoule with wires were homogenized at 800 ℃ for 48 hours and quenched into cold water. The composition and microstructure of as-spun wires and annealed wires were determined by a SEM equipped with a
thermal field emission gun (SEM, JEOL-6460). The transition temperatures of Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ samples were measured by differential scanning calorimetry (DSC, Perkin Elmer Pyris 1) at a heating/cooling rate of 10 °C/min. The crystal structures of Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ samples were determined by X-ray diffraction at room temperature (XRD, Dmax-2550V, Cu Kα, 40 KV, 100 mA).

**Results and discussion**

Fig.1 describes the external form of as-spun Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ alloy wires. As shown in Fig.1, the wires shows their diameter of $\sim$200μm and length of 3-10 cm. Because of the intrinsic brittleness of Ni-Mn-Ga alloys, Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ alloy wires are not long, quite different from other metal wires fabricated by the same INROWASP. The curve shape of Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ wires may be come from the wave of the water or not well optimized set of parameters.

Fig.2 shows the microstructure of INROWASP wires before and after annealing along their longitudinal and radial directions. The diameter of Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ wires is about 200μm. The structure of the as-spun wires are representative dendritic-like structures obtained in rapid solidified system, which is just like other results [8, 10]. There are two kinds of microstructure, dendritic-like and cellular structure [13, 17], in the rapid solidified Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ wires. The difference of the microstructures comes from the difference of the composition and cooling speed [8, 17]. Further studies are needed to specify this issue in more details for better understanding. Additionally, it is interesting to find from the Fig.1(c) and (d) that the microstructure of Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ wires were transformed from dendritic-like structure into bamboo grains structure by annealing. This bamboo grains structure resembles single grains spanning the whole wire cross-section. Although similar bamboo grains structure had been previously reported in other rapidly solidified Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ alloys (crucible melt extraction [9, 18], custom-built Taylor machine [12, 14]), there is little report about the transformation from dendritic-like structure to bamboo grains structure by annealing for Ni$_{55}$Mn$_{20.6}$Ga$_{24}$ wires. The special bamboo grains structure has two advantages. Firstly, for these individual grains, a large MFIS of Ni-Mn-Ga wires was measured in N. Scheerbaum paper [18]. Secondly, the special bamboo grains structure can be easily broken along the grain boundary into particles of single crystal while it is used to fabricate Ni-Mn-Ga/polymer composites [9]. Fig.2(c) and (d) show fully martensitic structure, indicating that the austenite/martensite transformation temperatures are above room temperature. It was confirmed in the following DSC and XRD results.
Fig. 2 Optical images of Ni\textsubscript{55}Mn\textsubscript{20.6}Ga\textsubscript{24.4} wire: (a),(b) as-spun, (c),(d) annealed (a),(c) longitudinal surface (b),(d) cross surface

Fig. 3 shows the DSC curves obtained in the as-spun and annealed states of Ni\textsubscript{55}Mn\textsubscript{20.6}Ga\textsubscript{24.4} wires. Compared to Fig 3(b), it was difficult to find the phase transformation in Fig 3(a). This phenomenon is different from other researcher's results as they found clear phase transformation from as extracted wires or as-spun wires [10, 11, 13]. This might caused by the large internal stress from large cooling speed in INROWASP and the large compositional homogeneity. Further investigations of this issue are needed in more detail for better understanding. Annealed wires exhibited a sharp and well-defined transformation between austenite and martensite compared with the somewhat smeared transformation in the as-spun wires, which was because heat treatment releases the internal stress and decreases the compositional homogeneity [7, 13]. However, some exceptional peaks occur on the martensitic transformation curve of the annealed wires. High transformation temperature can ensure that Ni\textsubscript{55}Mn\textsubscript{20.6}Ga\textsubscript{24.4} wires present martensitic phase at room temperature, which is good for MFIS property of Ni-Mn-Ga/polymer composite with these Ni-Mn-Ga wires used for fabricating composite.

Fig. 3 DSC curves of Ni\textsubscript{55}Mn\textsubscript{20.6}Ga\textsubscript{24.4} wires: (a) as-spin, (b) annealed

In order to confirm the martensitic phase at room temperature (Fig. 1 and Fig. 3), X-ray characterization of Ni\textsubscript{55}Mn\textsubscript{20.6}Ga\textsubscript{24.4} powders and annealed wires were performed (see Fig. 4). The XRD structure of Ni\textsubscript{55}Mn\textsubscript{20.6}Ga\textsubscript{24.4} powders was non-modulated martensitic structure which
corresponded to Pons' investigations [19]. In addition, the intensities of (622) reflections in annealed wires is relatively higher than that observed in the powder, suggesting that the annealed wires of Ni$_{55}$Mn$_{20.6}$Ga$_{24.2}$ have some preferential orientation. The similar observations of preferred orientation have been found in other researches [8, 20].

Fig. 4 XRD analysis for Ni$_{55}$Mn$_{20.6}$Ga$_{24.4}$ powders and wires

Conclusions

Ni$_{55}$Mn$_{20.6}$Ga$_{24.4}$(at%) wires were fabricated by the in rotating water melt-spinning technique(INROWASP). As-spun wires exhibits dendritic-like microstructure while bamboo grain microstructure is observed in the annealed wires. The peak temperatures of phase transformations of annealed wires are at 82.4°C and 70.5°C, corresponding to martensitic phase to austenitic phase, austenitic phase to martensitic phase, respectively. The crystal structure of annealed wires presents non-moderated martensite and preferred orientation at (622).

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